TOSHIBA Power Transistor Module Silicon PNP Epitaxial Type (Four Darlington Power Transistors in One)

MP4305

High Power Switching Applications

Hammer Drive, Pulse Motor Drive and Inductive Load Switching

- Small package by full molding (SIP 12 pin)
- High collector power dissipation (4 devices operation)
 PT = 4.4 W (Ta = 25°C)
- High collector current: IC(DC) = -5 A (max)
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = -5$ V, $I_{C} = -3$ A)
- Diode included for absorbing fly-back voltage

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	-100	V
Collector-emitter voltage		V _{CEO}	-100	V
Emitter-base voltage		V _{EBO}	-6	V
Collector current	DC	IC	-5	А
	Pulse	I _{CP}	-8	A
Continuous base current		ΙΒ	-0.5	Α
Collector power dissipation (1-device operation)		PC	2.2	W
Collector power dissipation (4-device operation)		P _T	4.4	W
Junction temperature		Tj	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C

Industrial Applications

TRANSISTOR PART

1, 5, 8, 12 BASE

2, 4, 9, 11 COLLECTOR

6, 7 EMITTER

DIODE PART

2, 4, 9, 11 CATHODE

3, 10 ANODE

JEDEC

JEITA

TOSHIBA

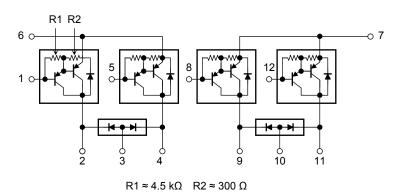
2-32C1E

Weight: 3.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

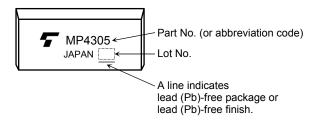
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Array Configuration



2006-10-27

Marking



Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	28.4	°C/W	
(4-device operation, Ta = 25°C)	3 (3)			
Maximum lead temperature for soldering purposes	TL	260	°C	
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	rrent	I _{CBO}	V _{CB} = -100 V, I _E = 0 A	_	_	-10	μΑ
Collector cut-off cu	rrent	I _{CEO}	V _{CE} = -100 V, I _B = 0 A	_	_	-10	μΑ
Emitter cut-off curre	ent	I _{EBO}	V _{EB} = -6 V, I _C = 0 A	-0.6	_	-2.0	mA
Collector-base brea	akdown voltage	V (BR) CBO	I _C = -1 mA, I _E = 0 A	-100	_	_	V
Collector-emitter bi	eakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0 A	-100	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = -5 V, I _C = -3 A	2000	_	15000	_
		h _{FE (2)}	V _{CE} = -5 V, I _C = -5 A	1000		_	
Saturation voltage	Collector-emitter	V _{CE} (sat)	$I_C = -3 \text{ A}, I_B = -6 \text{ mA}$	_	1	-1.5	V
Saturation voltage	Base-emitter	V _{BE} (sat)	$I_C = -3 \text{ A}, I_B = -6 \text{ mA}$	_	_	-2.0	
Transition frequency		f _T	$V_{CE} = -2 V, I_{C} = -0.5 A$	_	40	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0 A, f = 1 MHz	_	55	_	pF
Switching time Storage time Fall time	Turn-on time	t _{on}	Output B2 Output		0.3		
	Storage time	t _{stg}	20 µs B1 C1 C2 C3 C3 C4 C4 C4 C4 C4 C4		2.0		μs
	Fall time	t _f	$V_{CC} = -30 \text{ V}$ $-I_{B1} = I_{B2} = 6 \text{ mA}, \text{ duty cycle} \le 1\%$	_	0.4	_	

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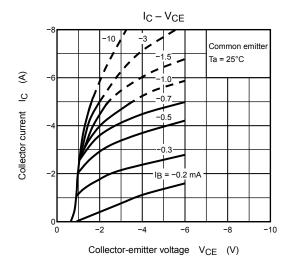
Emitter-Collector Diode Ratings and Characteristics (Ta = 25°C)

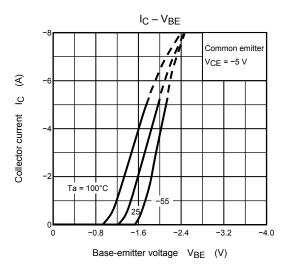
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}	_	_	_	3	Α
Surge current	I _{FSM}	t = 1 s, 1 shot	_	_	6	Α
Forward voltage	V _F	I _F = 1 A, I _B = 0 A	_	_	2.0	٧
Reverse recovery time	t _{rr}	I _F = 3 A, V _{BE} = 3 V, dI _F /dt = -50 A/μs	_	1.0	_	μs
Reverse recovery charge	Q _{rr}		_	8	_	μC

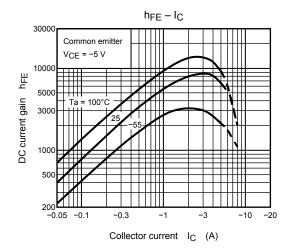
Flyback-Diode Rating and Characteristics (Ta = 25°C)

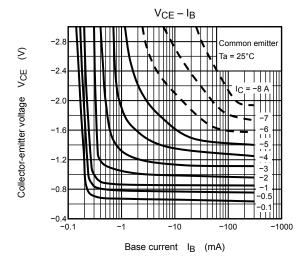
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}	_	_	_	3	Α
Reverse current	I _R	V _R = 110 V	_	_	0.4	μΑ
Reverse voltage	V _R	I _R = 100 μA	100	_	_	V
Forward voltage	V _F	I _F = 1 A	1	-	1.5	V

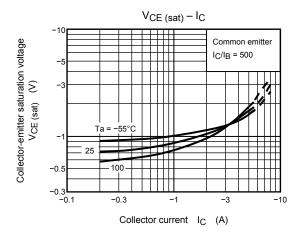
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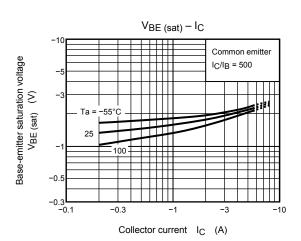


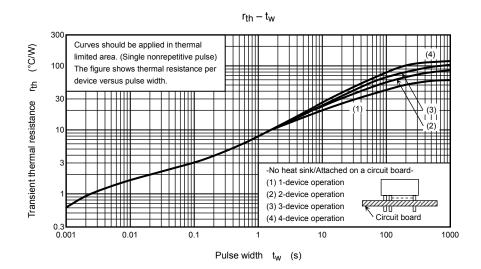


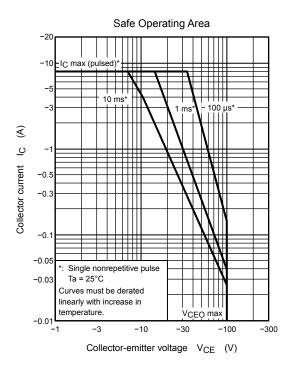


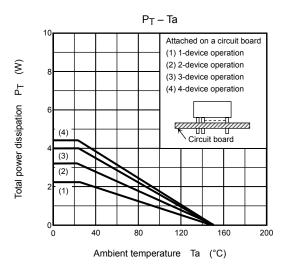


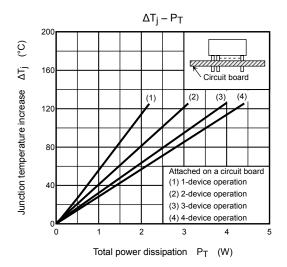












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